. WO 2005/086088 PCT/JP2005/003804

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### **EXPLANATION OF REFERENCE**

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100: integrated circuit, 101: light-receiving element, 102: light-emitting element, 103: antenna, 104: substrate, 105: cover material, 110 rectification circuit, 111 power supply circuit, 112: demodulation circuit, 113: logic circuit, 114: memory, 115: memory control circuit, 116: amplifier, 117: amplifier, 201: card body, 202: pixel portion, 203: light-receiving element, 204: light-emitting element, 205: substrate, 206: integrated circuit, 207: display device, 208: antenna, 210: rectification circuit, 211: power supply circuit, 212: demodulation circuit, 213: logic circuit, 214: memory, 215: memory control circuit, 216: amplifier, 217: amplifier, 218: control circuit, 219: signal line driver circuit, 220: scanning line driver circuit, 301: battery, 303: solar battery, 401: integrated circuit, 402: antenna, 403: substrate, 404: adhesive agent, 405: cover material, 406: adhesive agent, 407: IC card, 500: substrate, 501: separation layer, 502:base film, 503: semiconductor film, 504: semiconductor film, 505: semiconductor film, 508: gate insulating film, 509: gate electrode, 510: gate electrode, 513: resist, 514: resist, 515: low concentration impurity region, 518: resist, 519: high concentration impurity region, 520: insulating film, 521: sidewall, 525: resist, 526: high concentration impurity region, 527: high concentration impurity region, 528: high concentration impurity region, 529: n-channel TFT, 530: p-channel TFT, 531: n-channel TFT, 532: n-channel TFT, 533: interlayer insulating film, 534: interlayer insulating film, 535: wiring, 536: wiring, 538: wiring, 540: wiring, 541: wiring, 542: protective layer, 543: groove, 544: adhesive agent, 545: substrate, 546: bank, 547: electroluminescent layer, 548: electrode, 549: light-emitting element, 550: antenna, 551: adhesive agent, 552: cover material, 601: groove, 602: integrated circuit, 603: substrate, 604: separation layer, 605: broken line, 701: n-channel TFT, 702: p-channel TFT, 703: impurity region, 704: channel formation region, 705: semiconductor film, 706: gate insulating film, 707: gate electrode, 707a: conductive film, 708: sidewall, 709: sidewall, 710: LDD (Lightly Doped Drain) region, 711: semiconductor film, 712: impurity region, 713: channel formation region, 721: n-channel TFT, 722: p-channel TFT, 728: sidewall, 741: n-channel TFT, 742: p-channel TFT, 743: impurity region, 744: channel formation region, 745: semiconductor film,

WO 2005/086088 PCT/JP2005/003804

746: gate insulating film, 747: gate electrode, 748: protective film, 750: LDD (Lightly Doped Drain) region, 751: semiconductor film, 752: impurity region, 753: channel formation region, 1200: bank, 1201: wiring, 1202: wiring, 1203: terminal, 1204: electroluminescent layer, 1205: electrode, 1206: light-emitting element, 1207: adhesive agent, 1208: cover material, 1209: antenna, 1210: substrate, 1211: semiconductor element, 1215: base film, 1301: check, 1302: ID chip, 1303: ID chip, 1304: passport, 1305: ID chip, 1306: gift certificate, 1307: ID chip, 1308: packing material, 1309: boxed meal, 1310: label, 1311: ID chip, 1312: product, 1401: TFT, 1402: semiconductor film, 1403: gate insulating film, 1404: gate electrode, 1405: interlayer insulating film, 1406: interlayer insulating film, 1407: wiring, 1408: antenna, 1409: light-emitting element, 1411: TFT, 1412: semiconductor film, 1413: gate insulating film, 1414: gate electrode, 1418: antenna, 1419: light-emitting element, 1500: photodiode, 1501: interlayer insulating film, 1502: TFT, 1503: interlayer insulating film, 1504: cathode, 1505: photoelectric conversion layer, 1506: anode, 1510: substrate, 1511: photodiode, 15 1512: light-emitting element, 1513: shielding film, 6001: TFT, 6002: interlayer insulating film, 6003: light-emitting element, 6004: electrode, 6005: electroluminescent layer, 6006: electrode, 6007: interlayer insulating film, 6008: bank, 6009: wiring, 6011: TFT, 6013: light-emitting element, 6014: electrode, 6015: electroluminescent layer, 6016: electrode, 6021: TFT, 6023: light-emitting element, 6024: electrode, 6025: electroluminescent layer, 6026: electrode, 6029: wiring, 6031: TFT, 6033: light-emitting element, 6034: electrode, 6035:electroluminescent layer, 6036: electrode, 6039: wiring, 6041: TFT, 6043: light-emitting element, 6044: electrode, 6045: electroluminescent layer, 6046; electrode, 6051; TFT, 6053; light-emitting element, 6054; electrode, 6055; electroluminescent layer, 6056: electrode, 6059: wiring

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# INTERNATIONALSEARCHREPORT

International application No. PCT/JP2005/003804

## CLASSIFICATION OF SUBJECT MATTER

Int.CL.7G06K19/077, 19/07, H01L27/14, 27/15

According to International Patent Classification (IPC) or to both national classification and IPC

### FIELDS SEARCHED

Minimum documentation searched (classification system followed by classification symbols) Int.CL7G06K19/077, 19/07, H01L27/14, 27/15

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched
Published examined utility model applications of Japan 1922-1996
Published unexamined utility model applications of Japan 1971-2005
Registered utility model specifications of Japan 1996-2005
Published registered utility model applications of Japan 1994-2005

Electronic data base consulted during the international search (name of data base and, where practicable, search terms used)

C. DOCUMENTS CONSIDERED TO BE RELEVANT			
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Y	JP 01-502140 A (Froelich; R see the whole document & WO 1988/004453 A1 & US 4		1 - 16
Y	JP 2001-155134 A (Seiko 2001.06.08, lines 3 to 5, col 6 to line 1, column 7, figs. 4 none)	umn 5, line 27, column	1 - 16
<b>Y</b>	JP 2002-231909 A (Canon paragraphs [0017] - [0025], 4 & EP 1229582 A2 & US 2002/	[0034], [0035], figs.	1 - 16
Further documents are listed in the continuation of Box C.  Special categories of cited documents:  "A" document defining the general state of the art which is not considered to be of particular relevance  "E" earlier application or patent but published on or after the international filing date  "L" document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified)  "O" document referring to an oral disclosure, use, exhibition or other means  "P" document published prior to the international filing date but later than the priority date claimed  "A" document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to involve a inventive step when the document is taken alone  "Y" document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is taken alone  "Y" document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is taken alone  "Y" document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is taken alone  "Y" document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document of particular relevance; the claimed invention of the considered to involve an inventive s			erlying the invention he claimed invention cannot e considered to involve an staken alone the claimed invention cannot re step when the document is her such documents, such ion skilled in the art t family urch report
31.05.2005  Name and mailing address of the ISA/JP  Authorized officer  LEXT 2.0.4			
Name and mailing address of the ISA/JP  Japan Patent Office		Hiroshi MAEDA	5N 2943
3-4-3, Kasumigaseki, Chiyoda-ku, Tokyo 100-8915, Japan Telephone No. +81-3-3581-1101 Ext. 3586			

## INTERNATIONALSEARCHREPORT

International application No. PCT/JP2005/003804

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Y	<pre>JP 11-020360 A (Seiko Epson Corporation) 1999.01.26, paragraphs [0064], [0104] - [0116], figs. 20 - 22 (Family: none)</pre>	1 - 16
Y	JP 2001-257292 A (Hitachi Maxell LTD.) 2001.09.21, see the whole document (Family: none)	3 - 16
Y	JP 2002-083894 A (Hitachi Maxell LTD.) 2002.03.22, see the whole document & WO 2001/099193 A1 & US 2003/0116790 A1	3 - 16
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